

ME2803



Voltage Detectors, ME2803 Series

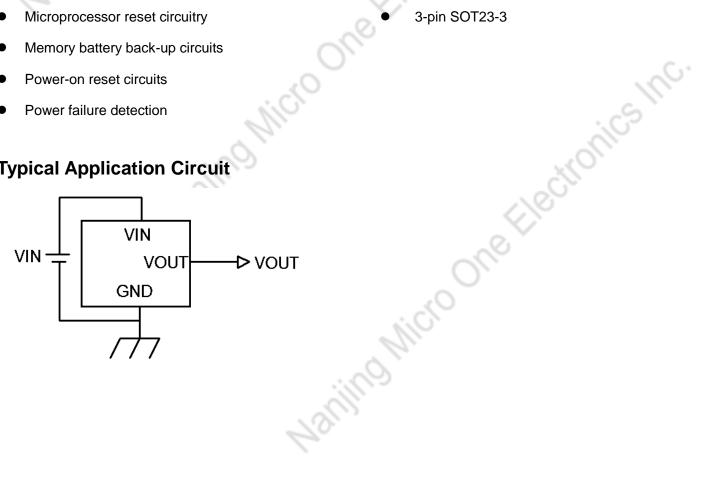
General Description

ME2803 Series are highly precise, low power consumption voltage detectors, manufactured using CMOS technologies. Detect voltage is extremely accurate with minimal temperature drift. CMOS output configurations are available.

Typical Application

- Microprocessor reset circuitry
- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection

Typical Application Circuit



Features

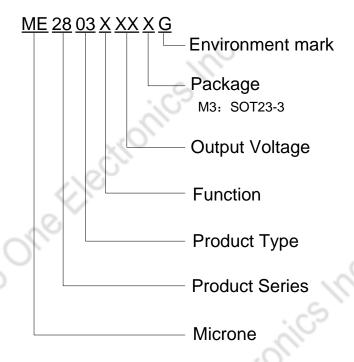
- Highly accuracy: ±1% (-VDET=1.5V above)
- Low power consumption: TYP 0.7uA (VIN=3.5V, -VDET=2.0V)
- Detect voltage range: 1.0V~6.5V in 0.1V increments
- Operating voltage range: 0.7V~7V
- Detect voltage temperature characteristics: TYP±100ppm/℃
- Output configuration: CMOS

Packages

3-pin SOT23-3



Selection Guide



product series	product description			
ME2803A10M3G	V _{OUT} =1.0V; Rising edge detection; Package: SOT23-3			
ME2803A11M3G	V _{OUT} =1.1V; Rising edge detection; Package: SOT23-3			
ME2803A14M3G	V _{OUT} =1.4V; Rising edge detection; Package: SOT23-3			
ME2803A16M3G	V _{OUT} =1.6V; Rising edge detection; Package: SOT23-3			
ME2803A18M3G	V _{OUT} =1.8V; Rising edge detection; Package: SOT23-3			
ME2803A19M3G	V _{OUT} =1.9V; Rising edge detection; Package: SOT23-3			
ME2803A22M3G	V _{OUT} =2.2V; Rising edge detection; Package: SOT23-3			
ME2803A25M3G	V _{OUT} =2.5V; Rising edge detection; Package: SOT23-3			
ME2803A26M3G	V _{OUT} =2.6V; Rising edge detection; Package: SOT23-3			
ME2803A27M3G	V _{OUT} =2.7V; Rising edge detection; Package: SOT23-3			
ME2803A28M3G	V _{OUT} =2.8V; Rising edge detection; Package: SOT23-3			
ME2803A30M3G	V _{OUT} =3.0V; Rising edge detection; Package: SOT23-3			
ME2803A33M3G	V _{OUT} =3.3V; Rising edge detection; Package: SOT23-3			
ME2803A34M3G	V _{OUT} =3.4V; Rising edge detection; Package: SOT23-3			
ME2803A35M3G	V _{OUT} =3.5V; Rising edge detection; Package: SOT23-3			
ME2803A38M3G	V _{OUT} =3.8V; Rising edge detection; Package: SOT23-3			

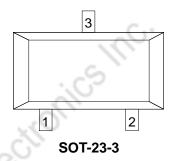
NOTE:

- 1. At present, there are sixteen kinds of voltage value:
 - 1.0V、1.1V、1.4V、1.6V、1.8V、1.9V、2.2V、2.5V、2.6V、2.7V、2.8V、3.0V、3.3V、3.4V、3.5V、3.8V。
- 2. If you need other voltage and package, please contact our sales staff.

V07 <u>www.microne.com.cn</u> Page 2 of 10



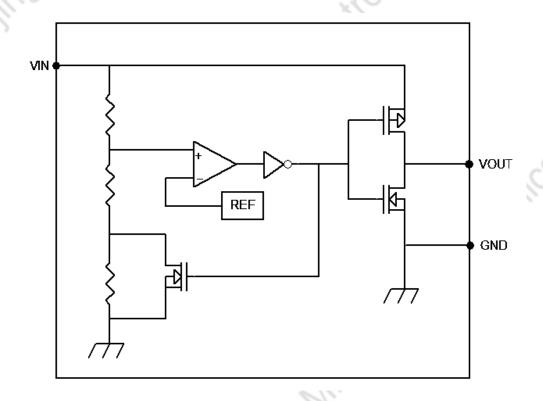
Pin Configuration



Pin Assignment

Pin Number SOT-23-3	Pin Name	Functions
2	GND	Ground
1	VOUT	Output Voltage
3	VIN	Input Voltage

Block Diagram



V07 <u>www.microne.com.cn</u> Page 3 of 10



Absolute Maximum Ratings

Paramet	Parameter		Ratings	Units
V _{IN} Input Vo	V _{IN} Input Voltage		8	V
Output Cur	Output Current		50	mA
Output Voltage	CMOS	V _{OUT}	GND-0.3~V _{IN} +0.3	V
Internal Power D	Internal Power Dissipation		0.54	W
Thermal resistance (Thermal resistance (Junction to air)		230	°C/W
Operating Ambient	Operating Ambient Temperature		-40~+85	$^{\circ}$ C
Maximum junction	temperature	TJ	-40~+150	$^{\circ}$ C
Storage Temp	erature	T _{stg}	-55~+150	$^{\circ}$ C
Soldering temperature and time		T _{solder}	260℃, 10s	
ESD		MM	400	V
		HBM	4000	V

Electrical Characteristics

 $(-V_{DET}(S)=1.0V \text{ to } 6.5V\pm1\% \text{ ,Ta}=25^{O}C \text{ ,unless otherwise noted)}$

Parameter	Symbol	Conditions	Min.	Тур	Max.	Units
Detect Voltage	-VDET	-VDET (S) ≦1.5V	-VDET (S) ×0.98	-VDET(S)	-VDET(S) ×1.02	V
		-VDET (S) >1.5V	-VDET (S) ×0.99	-VDET(S)	-VDET(S) ×1.01	
Hysteresis Range	VHYS	0/,	0.03	0.06	0.1	Cv
Supply Current	ISS	VIN=2V (1.0V-1.5V)	-	0.7	1	uA
		VIN =3.5V (1.6V-2.0V)	-	0.7	·(C)	
		VIN=4.5V (2.1V-3.9V)		1.2	2	
	- 0	VIN =6V (4.0V-5.6V)	-	1.1	2	
	20	VIN=7V (5.7V-6.5V)		1.0	2	
Output Current	lout N-ch	VDS=0.5V VIN =0.7V	0.01	0.14		mA
	lout P-ch	VDS=0.5V VIN =7V	1.7	3.4		mA
Operating voltage	VIN	-	0.7	-	7	V
Responding time	tpLH	On:			60	us
Temperature characteristics	∆ – VDET ∆Ta • –VDET	ΔTa =-40℃ ~ 85℃	-	±100	±350	ppm/℃

Note: $1 \cdot VDET(S)$: Specified Detection Voltage value

2、-VDET: Actual Detection Voltage value

3、Release Voltage: +VDET=-VDET+VHYS

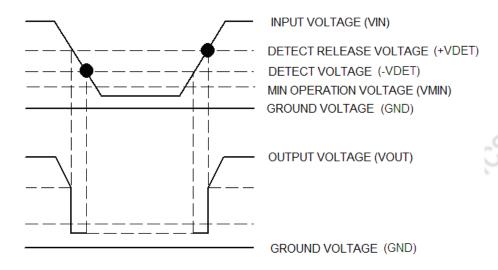


Functional Description:

- 1. When input voltage (V_{IN}) rises above detect voltage (–VDET), output voltage (V_{OUT}) will be equal to V_{IN}.
- When input voltage (V_{IN}) falls below detect voltage (–VDET), output voltage (V_{OUT}) will be equal to the ground voltage (GND) level.
- 3. When input voltage (V_{IN}) falls to a level below that of the minimum operating voltage (V_{MIN}) , output will become unstable. In this condition, V_{IN} will equal the pulled-up output (should output be pulled-up.)
- 4. When input voltage (V_{IN}) rises above the ground voltage (GND) level, output will be unstable at levels below the minimum operating voltage (V_{MIN}). Between the VMIN and detect release voltage +VDET) levels, the ground voltage (GND) level will be maintained.
- 5、 When input voltage (VIN) rises above detect release voltage (+VDET), output voltage (VOUT) will be equal to VIN.
- 6. The difference between +VDET and –VDET represents the hysteresis range.

Timing Chart

ME2803XX:



Directions for use

- 1. Please use this IC within the stated maximum ratings. Operation beyond these limits may cause degrading or permanent damage to the device.
- 2. When a resistor is connected between the V_{IN} pin and the input with CMOS output configurations, oscillation may occur as a result of voltage drops at R_{IN} if load current(I_{OUT}) exists.(refer to the Oscillation Description(1) below)
- 3. When a resistor is connected between the V_{IN} pin and the input with CMOS output configurations, oscillation may occur as a result of through current at the time of voltage release even if load current(I_{OUT}) does not exist. (refer to the Oscillation Description(2) below)
- 4. With a resistor connected between the V_{IN} and the input, detect and release voltage will rise as a result of the IC's

V07 www.microne.com.cn Page 5 of 10



supply current flowing through the V_{IN} pin.

5. In order to stabilize the IC's operations, please ensure that V_{IN} pin's input frequency's rise and fall times are more than several u Sec/V.

Oscillation Description

1. Output current oscillation with the CMOS output configuration

When the voltage applied at IN rises, release operations commence and the detector's output voltage increase. Load current (I_{OUT}) will flow at R_L . Because a voltage drop ($R_{IN}^*I_{OUT}$) is produces at the R_{IN} resistor, located between the input (IN) and the V_{IN} pin. The load current will flow via the IC's pin. The voltage drop will also lead to a fall in the voltage level at the V_{IN} pin. When the V_{IN} pin voltage level falls below the detect voltage level, detect operations will commence. Fllowing detect operations, load current flow will cease and since voltage drop at R_{IN} will disapper, the voltage level at the V_{IN} pin will rise and release operations will begin over again. Oscillation may occur with this "release-detect-release" repetition. Further, this condition will also appear via means of a similar mechanism during detect operations.

2. Oscillation as a result of through current

Since the ME2803 series are CMOS IC's, through current will flow when the IC's internal circuit switching operates (during release and detect operations). Consequently, oscillation is liable to occur as a result of drops in voltage at the through current's resistor (R_{IN}) during release voltage operations.(refer to diagram 2) since hysteresis exists during detect operations, oscillation is unlikely to occur.

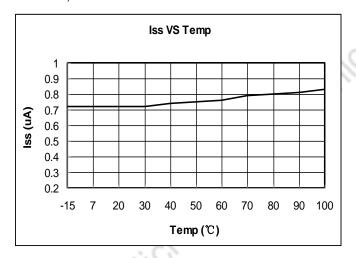
V07 www.microne.com.cn Page 6 of 10



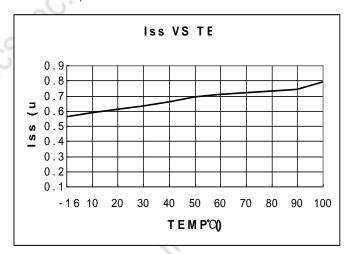
Type Characteristics

1. Supply Current Vs. Ambient Temperature

VIN=2V,-VDET=1.1V

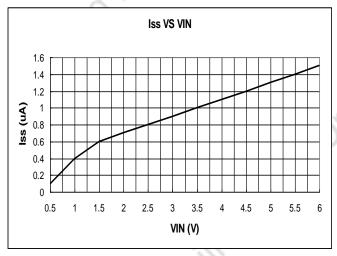


VIN=3V,-VDET=2.2V

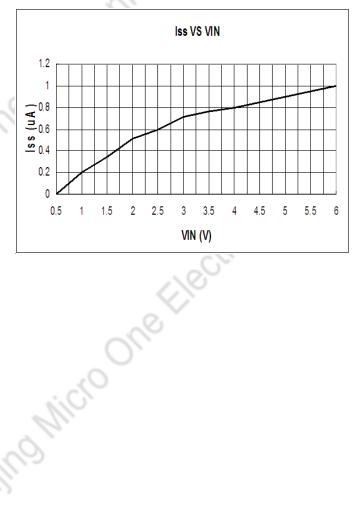


2. Supply Current Vs. Input Voltage

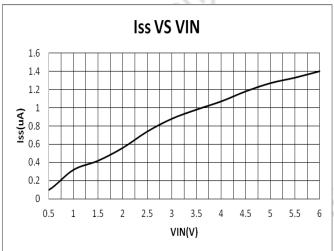
-VDET=1.1V (T=25°C)



-VDET=2.2V (T=25°C)



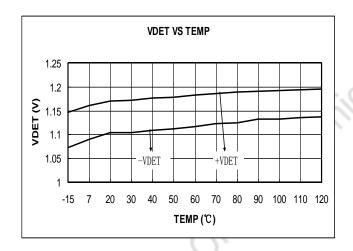
-VDET=2.5V (T=25°C)



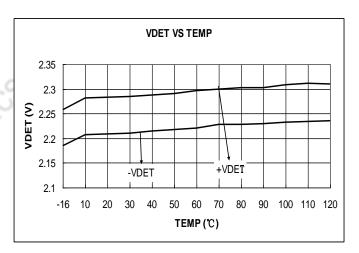


3. Detect, Release Voltage Vs. Ambient Temperature

-VDET=1.1V

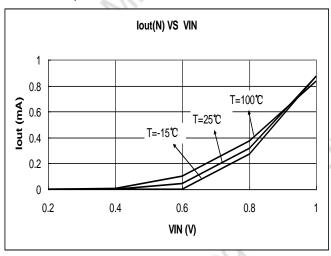


-VDET=2.2V

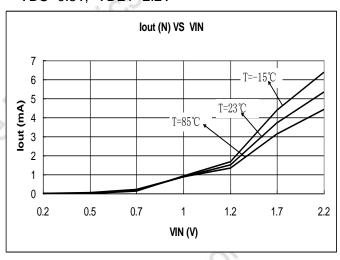


4、N-Ch Output Current Vs. Input Voltage

VDS=0.5V, -VDET=1.1V

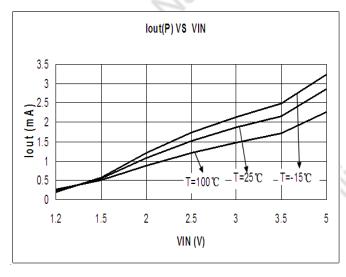


VDS=0.5V, -VDET=2.2V

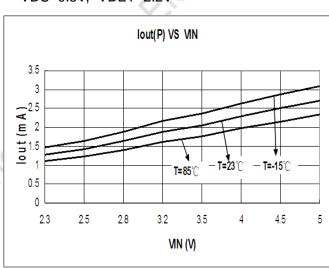


5、P-Ch Output Current Vs. Input Voltage

VDS=0.5V, -VDET=1.1V



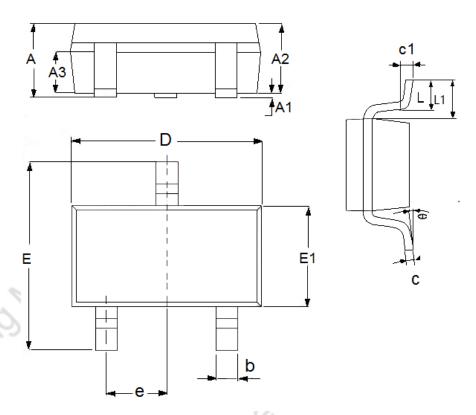
VDS=0.5V, -VDET=2.2V





Packaging Information

• Package Type: SOT23-3



DIM	Millime	Millimeters		Inches		
DIM	Min	Max	Min	Max		
Α	1.05	1.45	0.0413	0.0571		
A1	0	0.15	0.0000	0.0059		
A2	0.9	1.3	0.0354	0.0512		
A3	0.6	0.7	0.0236	0.0276		
b	0.25	0.5	0.0098	0.0197		
С	0.1	0.25	0.0039	0.0098		
D	2.8	3.1	0.1102	0.1220		
Е	2.6	3.1	0.1023	0.1220		
E1	1.5	1.8	0.0591	0.0709		
е	0.95(TYP)		0.0374(TYP)			
L	0.25	0.6	0.0098	0.0236		
L1	0.59(TYP)		0.0232(TYP)			
θ	0	8°	0.0000	8°		
c1	0.2(TYP)		0.0079(TYP)			



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V07 www.microne.com.cn Page 10 of 10